





# U308, U309 N-Channel JFET

Technical

Support

#### Features

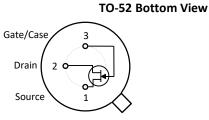
- InterFET <u>N0072L Geometry</u>
- Low Noise: 2 nV/VHz Typical
- Low Ciss: 4pF Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

### Applications

- Mixers
- Oscillators
- VHF/UHF Amplifiers

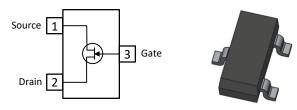
### Description

The -25V InterFET U308 and U309 are targeted for higher gain VHF amplifiers, mixers, and oscillators. Gate leakages are typically less than 10pA at room temperatures.

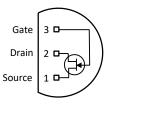




#### SOT23 Top View



### TO-92 Bottom View





#### **Product Summary**

	Parameters	U308 Min	U309 Min	Unit		
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-25	-25	V		
I <sub>DSS</sub>	Drain to Source Saturation Current	12	12	mA		
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-1	-1	V		
GFS	Forward Transconductance	10	10	mS		

#### Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
U308; U309	Through-Hole	TO-52	Bulk
PNU308; PNU309	Through-Hole	TO-92	Bulk
SMPU308; SMPU309	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMPU308TR; SMPU309TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
U308COT; U309COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
U308CFT; U309CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







# **Electrical Characteristics**

### Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	-25	V
$I_{FG}$	Continuous Forward Gate Current	20	mA
PD	Continuous Device Power Dissipation	500	mW
Р	Power Derating	4	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 200	°C

### Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			U308		U309				
	Parameters	Conditions	Min	Тур	Max	Min	Тур	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	$V_{DS} = 0V$ , $I_G = -1\mu A$	-25			-25			V
Igss	Gate to Source Reverse Current	V <sub>GS</sub> = -15V, V <sub>DS</sub> = 0V, T <sub>A</sub> = 25°C V <sub>GS</sub> = -15V, V <sub>DS</sub> = 0V, T <sub>A</sub> = 125°C			-150 -150			-150 -150	pA nA
V <sub>GS(OFF)</sub>	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1nA	-1		-6	-1		-4	v
V <sub>GS(F)</sub>	Gate to Source Forward Voltage	V <sub>DS</sub> = 0V, I <sub>G</sub> = 10mA			1			1	v
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 0V, V_{DS} = 15V$ (Pulsed)	12		60	12		30	mA

### Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			U308		U309				
	Parameters	Conditions	Min	Тур	Max	Min	Тур	Max	Unit
	Forward	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 1kHz	10	17		10	17		
GFS	Transconductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz		15			15		mS
	Transconductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 450MHz		14			14		
		V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 1kHz			250			250	
Gos	Output Conductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz		0.18			0.18		μS
		V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 450MHz		0.32			0.32		
C	Power Gain	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz	14	16		14	16		dB
Gps	Power Galli	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 450MHz	10	11		10	11		ив
C <sub>dg</sub>	Drain Gate	$V_{DS} = 10V. V_{GS} = -10V. f = 1MHz$			2.5			2.5	pF
Cag	Capacitance	VDS = 10V, VGS = -10V, I = 11VII 12			2.5			2.5	pi
Cgs	Source Gate	$V_{DS} = 10V, V_{GS} = -10V, f = 1MHz$			5			5	pF
Cgs	Capacitance	VDS - 10V, VGS10V, I - 11VII 12			5			5	рі
en	Noise Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 100kHz			10			10	nV/√Hz
		V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz		1.5	2		1.5	2	db
NF	Noise Figure	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 450MHz		2.7	3.5		2.7	3.5	dB



Technical

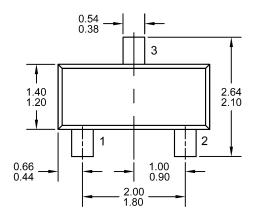
Support

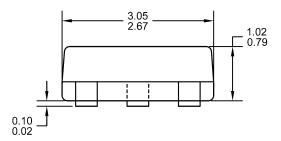
Order

Now

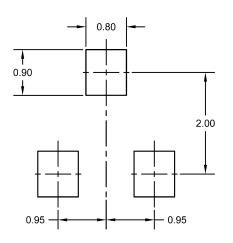
# SOT23 (TO-236AB) Mechanical and Layout Data

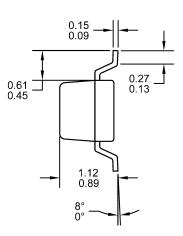
### **Package Outline Data**





### Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

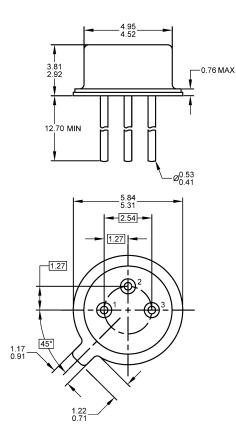




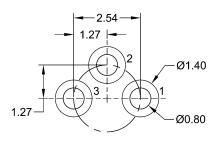
Now

## **TO-52 Mechanical and Layout Data**

### **Package Outline Data**



### **Suggested Through-Hole Layout**



- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.26 grams
- 3. Bulk product is shipped in standard ESD shipping material
- 4. Refer to JEDEC standards for additional information.

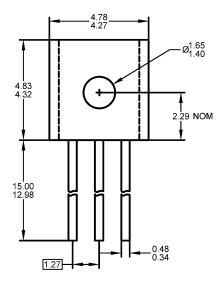
- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

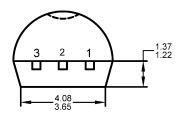




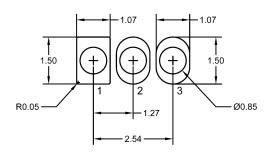
### **TO-92 Mechanical and Layout Data**

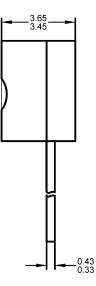
### Package Outline Data





### Suggested Through-Hole Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

InterFET:

<u>U309</u> <u>U308</u> <u>SMPU308</u> <u>SMPU309</u>